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NATIONAL STANDARD OF THE

PEOPLE'S REPUBLIC OF CHINA

GB/T 4023.15-2026

Discrete semiconductor devices-Part 15: Isolated power semiconductor devices

半导体分立器件 第15部分：绝缘功率半导体器件

(English Translation)

Issued on: October 30, 2026 **Implemented on: May 1, 2027**

Issued by: State Administration for Market Regulation;
Standardization Administration of China

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https://chinastandards.org/standards/gb-t-4023-15-2026

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1 Foreword

GB/T 4023.15-2026 was issued by State Administration for Market Regulation; Standardization Administration of China on 30 October 2026 and takes effect on 1 May 2027.

It is one of 8 parts of the GB/T 4023 series.

The GB/T prefix marks a recommended standard. It is not law in itself: it becomes binding when a contract names it, when a regulation or a mandatory standard refers to it, or when a producer declares conformity with it.

2 Scope Preview

GB/T 4023.15-2026 carries no ICS number and no Chinese Standard Classification code.

This catalogue holds 76,457 other GB/T standards.

Of the 47,415 GB/T standards that do carry an ICS number, 3,437 (7%) fall under ICS 77, in the field of metallurgy.

3 About this standard

Issued by: State Administration for Market Regulation; Standardization Administration of China

4 Related standards

Other parts of this standard:

GB/T 4023-1997 - Semiconductor devices Discrete devices and integrated circuits Part 2: Rectifier diodes

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GB/T 4023-2015 - Discrete semiconductor devices - Part 1: Sectional specification

GB/T 4023.1-2026 - Discrete semiconductor devices - Part 1: Sectional specification

GB/T 4023.2-2026 - Discrete semiconductor devices - Part 2: Rectifier diodes

GB/T 4023.3-2026 - Discrete semiconductor devices - Part 3: Signal, switching and regulator diodes

GB/T 4023.4-2026 - Discrete semiconductor devices - Part 4: Microwave diodes and transistors

GB/T 4023.8-2026 - 8:Field-effect transistors

5 Classification and status

Prefix GB/T: recommended standard.

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